

	Type	Hits	Search Text	DBs
1	IS&R	1	("9346283").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
2	IS&R	2	("5324980").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
3	IS&R	2	("5501990").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
4	IS&R	8	((("5363952") or ("5541372") or ("5471405") or ("5339090")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
5	BRS	971	(logic or microprocessor) and display and sensor and (semiconductor adj substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
6	BRS	357	S5 and @ad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
7	BRS	338	S5 and @rlad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
8	BRS	541	S6 S7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
9	BRS	12	S9 and @ad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
10	BRS	1	S9 and @rlad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
11	BRS	13	S10 S11	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
12	BRS	161	(logic or microprocessor or CMOS) same (display or visual or pixel or pixels or led or leds or (light adj emitting)) same (sensor or micromechanical or microengineered or ((strain or thermal or radiation or chemical\$3) near1 gauge)) same (semiconductor adj substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
13	BRS	0	("2002/0113284").URPN.	USPAT
14	BRS	26116	((micromechanical or microengineered) near2 sensor) or ((strain or thermal or radiation or chemical\$3) near1 gauge)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
15	BRS	4606	((micromechanical or microengineered) near2 sensor) or ((strain or thermal or radiation or chemical\$3) near1 gauge)).ti.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
16	BRS	278031	semiconductor near2 substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
17	BRS	7855	"same" near2 S16	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
18	BRS	12	S14 and S17	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
19	BRS	1	S15 and S17	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
20	BRS	12	S19 S18	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
21	BRS	6648	(display or visual or pixel or pixels or led or leds or (light adj emitting)) and S14	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
22	BRS	2845	(logic or microprocessor or CMOS or processor) and S21	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
23	BRS	61	S22 and S16	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
24	BRS	7	S23 and @ad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
25	BRS	8	S23 and @rlad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
26	BRS	10	S24 S25	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
27	BRS	175316	(piezoelectric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
28	BRS	33525	(display or visual or pixel or pixels or led or leds or (light adj emitting)) and S27	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
29	BRS	13342	(logic or microprocessor or CMOS or processor) and S28	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
30	BRS	684	S29 and S16	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
31	BRS	188	S30 and @ad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
32	BRS	223	S30 and @rlad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
33	BRS	327	S31 S32	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
34	BRS	9387	(display or visual or pixel or pixels or led or leds or (light adj emitting)) same S27	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
35	BRS	1	(piezoelectric) same (logic or microprocessor or CMOS or processor) same (display or visual or pixel or pixels or led or leds or (light adj emitting)) same (semiconductor near2 substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
36	IS&R	3317	(361/681,686,717,718).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
37	BRS	11851536	"2" and @ad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
38	BRS	0	S37 and @rlad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
39	BRS	5	((micromechanical or microengineered or piezoelectric or microelectric) near5 sensor) or ((strain or thermal or radiation or chemical\$3) near1 gauge)) and S36	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
40	IS&R	2492	(345/204-207).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
41	IS&R	2	("0000015").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
42	BRS	5789	S36 S40	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
43	BRS	13	((micromechanical or microengineered or piezoelectric or microelectric) near5 sensor) or ((strain or thermal or radiation or chemical\$3 or pressure) near1 gauge)) and S42	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
44	BRS	13	((micromechanical or microengineered or piezoelectric or microelectric) near5 sensor) or ((pressure or strain or thermal or radiation or chemical\$3 or pressure) near1 gauge)) and S42	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
45	IS&R	4052	(345/204-207, 98, 104, 108).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
46	IS&R	4	("5812191").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
47	IS&R	2	("6274861").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
48	BRS	14619	((temperature or radiation or pressure or inertial or light or ir or rf) near2 (sensor or gauge)) or accelerometer) and (display or pixel or (gallium near1 arsenide) or GaAs or pixels) and (((logic or control) adj circuit) or cmos)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
49	BRS	1240	((temperature or radiation or pressure or inertial or light or ir or rf) near2 (sensor or gauge)) or accelerometer) same (display or pixel or (gallium near1 arsenide) or GaAs or pixels) same (((logic or control) adj circuit) or cmos)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
50	BRS	269	((temperature or radiation or pressure or inertial or light or ir or rf) near2 (sensor or gauge)) or accelerometer) near15 (display or pixel or (gallium near1 arsenide) or GaAs or pixels) near15 (((logic or control) adj circuit) or cmos)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
51	BRS	7973	S48 and @ad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
52	BRS	3704	S48 and @rlad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
53	BRS	9239	S51 S52	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
54	BRS	668	S49 and @ad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
55	BRS	182	S49 and @rlad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
56	BRS	739	S54 S55	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
57	BRS	56	S50 and @rlad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
58	BRS	137	S50 and @ad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
59	BRS	162	S57 S58	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
60	BRS	528	(semiconductor near3 substrate) and S53	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
61	BRS	15	(semiconductor near3 substrate) and S56	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
62	BRS	9	(semiconductor near3 substrate) and S59	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
63	BRS	6	S61 not S62	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
64	BRS	513	S60 not S61	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
65	BRS	519	S60 not S62	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
66	BRS	519	S64 S65	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
67	BRS	14619	((((temperature or radiation or pressure or inertial or light or ir or rf) near2 (sensor or gauge)) or accelerometer) and (display or pixel or (gallium near1 arsenide) or GaAs or pixels) and (((logic or control) adj circuit) or cmos)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
68	BRS	1240	((((temperature or radiation or pressure or inertial or light or ir or rf) near2 (sensor or gauge)) or accelerometer) same (display or pixel or (gallium near1 arsenide) or GaAs or pixels) same (((logic or control) adj circuit) or cmos)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
69	BRS	269	((temperature or radiation or pressure or inertial or light or ir or rf) near2 (sensor or gauge)) or accelerometer) near15 (display or pixel or (gallium near1 arsenide) or GaAs or pixels) near15 (((logic or control) adj circuit) or cmos)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
70	BRS	7973	S67 and @ad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
71	BRS	3704	S67 and @rlad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
72	BRS	9239	S70 S71	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
73	BRS	668	S68 and @ad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
74	BRS	182	S68 and @rlad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
75	BRS	739	S73 S74	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
76	BRS	56	S69 and @rlad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
77	BRS	137	S69 and @ad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
78	BRS	162	S76 S77	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
79	BRS	528	(semiconductor near3 substrate) and S72	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
80	BRS	15	(semiconductor near3 substrate) and S75	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
81	BRS	9	(semiconductor near3 substrate) and S78	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
82	BRS	513	S79 not S80	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
83	BRS	519	S79 not S81	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
84	BRS	513	S82 and S83	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
85	BRS	256	((common or single or "same") near2 substrate) and S84	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
86	BRS	294	transparent near1 substrate near1 semiconductor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
87	BRS	6068	(transparent near1 substrate).ti.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
88	BRS	9350	(transparent near1 substrate).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
89	BRS	3909	semiconductor and S88	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
90	BRS	318	((transparent near1 substrate) near5 semiconductor).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
91	BRS	2766	(transparent near1 substrate near2 (comprised or comprises or comprising or including or includes or selected)).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
92	BRS	816	((transparent near1 substrate) adj2 (comprised or comprises or comprising or including or includes or selected)).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
93	BRS	591	((transparent near1 substrate) adj1 (comprised or comprises or comprising or including or includes or selected)).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
94	BRS	276	S93 and @ad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
95	BRS	97	S93 and @rlad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
96	BRS	308	S94 S95	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
97	BRS	1060	((transparent near1 substrate) adj1 (comprised or comprises or comprising or including or includes or selected))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
98	BRS	508	S97 and @ad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
99	BRS	156	S97 and @rlad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
100	BRS	4	S100 and @ad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
101	BRS	1	S100 and @rlad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
102	BRS	5	S101 S102	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
103	BRS	18	((transparent near1 substrate) adj1 (comprised or comprises or comprising or including or includes or selected))near15 (gallium or ga or gaas or gap or gain or sic or carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
104	BRS	23	((transparent near1 substrate) adj1 (comprised or comprises or comprising or including or includes or selected))with (gallium or ga or gaas or gap or gain or sic or carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
105	BRS	5	S104 not S100	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
106	BRS	226	((transparent near1 substrate) with semiconductor) and display and sensor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
107	BRS	103	S106 and @ad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
108	BRS	101	S106 and @rlad<"19990701"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
109	BRS	149	S107 S108	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB